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APPLICATION NO	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO	CONFIRMATION NO	
10 767.276	01 29 2004	Kern-Huat Ang	TS02-1330	4291	
8933	8933 7590 05 03 2005			EXAMINER	
DUANE MORRIS, LLP IP DEPARTMENT			PHAM, THANHHA S		
ONE LIBERTY PLACE			ART UNIT	PAPER NUMBER	
PHILADELPHIA, PA 19103-7396			2813		

DATE MAILED: 05 03 2005

Please find below and or attached an Office communication concerning this application or proceeding.

Applicant(s) Application No. 10/767.276 ANG ET AL Office Action Summary Examiner Art Unit Tranhna Pham 2813

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filled attac SIX -5.110NTHS from the mallion date of this common model.

S	t	a	t	u	S

 1NO period for regity is specified above, the maximum statuting Failure to reply within the set or extended period for reply will, by 	is a reply within the statutory minimum of thirty (30) days will be considered timely period will apply and will expire SIX (6) MONTHS from the making date of this conimum cation statute, cause the application to become ABANDONED (35 U.S.C. § 133). It is mailing date of this communication, even if timely filled, may reduce any
Status	
1) Responsive to communication(s) filed on	<u>01 March 2005</u> .
2a) ☐ This action is FINAL . 2b) ☐	This action is non-final.
3) Since this application is in condition for a	llowance except for formal matters, prosecution as to the merits is
closed in accordance with the practice ur	nder <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.
Disposition of Claims	
4) Claim(s) 1-27 and 42 is/are pending in th	e application.
4a) Of the above claim(s) is/are wi	
5) Claim(s) is/are allowed.	
6) ☑ Claim(s) <u>1-27 and 42</u> is/are rejected.	
7) Claim(s) is/are objected to.	
8) Claim(s) are subject to restriction	and/or election requirement.
Application Papers	
9)⊠ The specification is objected to by the Exa	aminer.
10) The drawing(s) filed on 29 January 2004	is/are: a) \square accepted or b) \boxtimes objected to by the Examiner.
	to the drawing(s) be held in abeyance. See 37 CFR 1.85 a)
Replacement drawing sheet(s) including the d	correction is required if the drawing(s) is objected to [See 37 CFR 1 121.5]
11) The oath or declaration is objected to by t	he Examiner. Note the attached Office Action or form PTO-152.
Priority under 35 U.S.C. § 119	
12) Acknowledgment is made of a claim for fo	preign priority under 35 U.S.C. § 119(a)-(d) or (f).
a) All b) Some * c) None of:	3 (, (, (,)
1. Certified copies of the priority docu	ments have been received.
	ments have been received in Application No
	e priority documents have been received in this National Stage
application from the International E	Bureau (PCT Rule 17.2(a)).
* See the attached detailed Office action for	a list of the certified copies not received.
Attachment(s)	
	4 Interview Summary PTC-413
D Table of Erattspersun's Parent Drawing Review PTC-94	4
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	nformatiun Discipsure Statement's II PTO-1449 or PTO SB 08	5) Notice of informal Patent Application, PTC-15
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	Paper No.s. Mai Dure 33,29,0003	∂ Cther

DETAILED ACTION

This Office Action is in response to Applicant's Amendment dated 03/01/2005.

Oath/Declaration

1. Oath/Declaration filed on 01/09/2004 has been considered.

Drawings

- 2. The drawings are objected to as failing to comply with 37 CFR 1.84(p)(4) because reference characters "124" and "80" of figures 11 & 12 have both been used to designate the same layer of HDP oxide. Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. Each drawing sheet submitted after the filing date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.
- 3 The drawings are objected to under 37 CFR 1.83(a). The drawings must show every feature of the invention specified in the claims. Therefore, the "conformal oxide layer" overlying said plurality of conductive lines prior to said step of depositing a high

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density plasma (HDP) oxide layer of claim 2 must be shown or the feature(s) canceled from the claim(s). No new matter should be entered.

Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet, and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. Each drawing sheet submitted after the filling date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Specification

- 4. The disclosure is objected to because of informalities.
 - Specification page 18, lines 1 and 8, typographical error "the polish stopping layer 80" should be changed to "the polish stopping layer 100"

Specification page 19. I:nes 6-8. it is not clear how the second stage of CMP processing can first remove the thin film layer 104 overlying the second polysilicon layer 72 when the thin film 104 is already polished down to the polish stop layer 100 overlying the second planar top surfaces 96 of the HDP oxide layer 80 (see page 17-18 and figure 9 for details)

Appropriate correction is required.

5. The specification is objected to as failing to provide proper antecedent basis for the claimed subject matter. See 37 CFR 1.75(d)(1) and MPEP § 608.01(o). Correction of the following is required: The specification must be corrected to support original claim 2 including depositing a conformal oxide layer overlying said plurality of conductive lines prior to said step of depositing a high density plasma (HDP) oxide layer overlying said substrate and said conductive lines.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

- 6. Claims 1-27 and 42 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.
- ▶ With respect to claim 1.

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lines 11-12, polishing down said film layer to said polish stopping layer overlying said second planar top surfaces" renders the claim indefinite. It is not clear where "said second planar top surfaces" are located and come from.

lines 13-15. "polishing down said film layer, said polish stopping layer, and said conductive lines to said polish stopping layer overlying said first planar top surfaces to complete said polishing down of said conductive lines" renders the claim indefinite as being incomplete for omitting essential steps, such omission amounting to a gap between the steps. See MPEP § 2172.01. The omitted step is polishing down "said high density plasma (HDP) oxide layer". It is not clear how said conductive lines are polished down without polishing said high density plasma (HDP) oxide layer (see figures 9-10 for details) when said high density plasma (HDP) oxide layer still overlying (covering) conductive lines

- With respect to claim 2. It is not clear how said conductive lines are polished down without polishing said "conformal oxide layer overlying said conductive lines being formed prior to said step of depositing high density plasma (HDP) oxide layer.
- ► With respect to claim 4.

line 6, "pattering" should be changed to "patterning"

With respect to claim 7.

it is not clear where "said step of sputtering down said HDP oxide layer" comes from

➤ With respect to claim 11.

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line 5. "first planar surfaces" should be changed to "first planar top surfaces" (see claim 11 line 14 for details)

lines 7-8, "second planar surfaces" should be changed to "second planar top surfaces (see claim 11 lines 11-12 for details)

lines 13-15. "polishing down said film layer, said polish stopping layer, and said polysilicon lines to said polish stopping layer overlying said first planar top surfaces to complete said polishing down of said polysilicon lines" renders the claim indefinite as being incomplete for omitting essential steps, such omission amounting to a gap between the steps. See MPEP § 2172.01. The omitted step is polishing down "said high density plasma (HDP) oxide layer". It is not clear how said polysilicon lines are polished down without polishing said high density plasma (HDP) oxide layer (see figures 9-10 for details) when said high density plasma (HDP) oxide layer still overlying (covering) said polysilicon lines

► With respect to claim 19.

lines 5-6, "first planar surfaces" should be changed to "first planar top surfaces" (see claim 19 line 14 for details)

line 8. "second planar surfaces" should be changed to "second planar top surfaces" (see claim 19 lines 11-12 for details)

lines 13-15, "polishing down said film layer, said polish stopping layer, and said n-type polysilicon lines to said polish stopping layer overlying said first planar top surfaces to complete said pol shing down of said n-type polysilicon lines," renders the claim indefinite as being incomplete for omitting essential

steps, such omission amounting to a gap between the steps. See MPEP § 2172 01. The omitted step is polishing down "said high density plasma (HDP) oxide layer". It is not clear how said n-type polysilicon lines can be polished down without polishing said high density plasma (HDP) oxide layer (see figures 9-10 for details) when said high density plasma (HDP) oxide layer still overlying (covering) said n-type polysilicon lines.

line 19 "said oxide layer" lacking antecedent basis should be changed to "said dielectric layer".

► With respect to claim 22,

it is not clear that "said polysilicon lines" refers to "said n-type polysilicon lines" or "said p-type polysilicon lines".

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thanhha Pham whose telephone number is (571) 272-1696. The examiner can normally be reached on Monday and Thursday 9:00AM - 9:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor. Carl Whitehead can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thanhha Pham Patent Examiner

Patent Examining Group 2800